

**HIGH EFFICIENCY RECTIFIER**

**VOLTAGE RANGE 50 to 1000 Volts CURRENT 5.0 Ampere**

**FEATURES**

- \* Low power loss, high efficiency
- \* Low leakage
- \* Low forward voltage drop
- \* High current capability
- \* High speed switching
- \* High reliability
- \* High current surge

**MECHANICAL DATA**

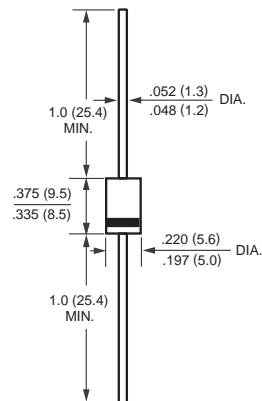
- \* Case: Molded plastic
- \* Epoxy: Device has UL flammability classification 94V-0
- \* Lead: MIL-STD-202E method 208C guaranteed
- \* Mounting position: Any
- \* Weight: 1.20 grams

**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

Ratings at 25 °C ambient temperature unless otherwise specified.  
 Single phase, half wave, 60 Hz, resistive or inductive load.  
 For capacitive load, derate current by 20%.



**DO-201AD**



Dimensions in inches and (millimeters)

**MAXIMUM RATINGS** (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	HER501	HER502	HER503	HER504	HER505	HER506	HER507	HER508	UNITS
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	300	400	600	800	1000	Volts
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	210	280	420	560	700	Volts
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	300	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at TA= 50°C	I <sub>O</sub>	5.0								Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	I <sub>FSM</sub>	200				150				Amps
Typical Junction Capacitance (Note 2)	C <sub>J</sub>	70				50				pF
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to + 150								°C

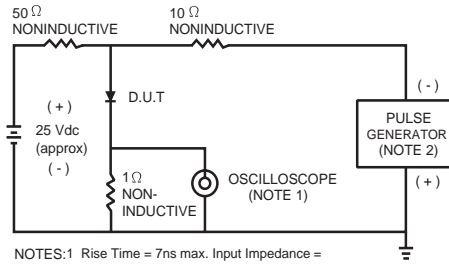
**ELECTRICAL CHARACTERISTICS** (At TA = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	HER501	HER502	HER503	HER504	HER505	HER506	HER507	HER508	UNITS
Maximum Instantaneous Forward Voltage at 5.0A DC	V <sub>F</sub>	1.0		1.3		1.7				Volts
Maximum DC Reverse Current at Rated DC Blocking Voltage TA = 25°C	I <sub>R</sub>	10				150				uAmps
Maximum Full Load Reverse Current Average, Full Cycle .375" (9.5mm) lead length at TL = 55°C		50				75				nSec
Maximum Reverse Recovery Time (Note 1)	t <sub>rr</sub>	50				75				nSec

NOTES : 1. Test Conditions: I<sub>F</sub> = 0.5A, I<sub>R</sub> = -1.0A, I<sub>RR</sub> = -0.25A  
 2. Measured at 1 MHz and applied reverse voltage of 4.0 volts

# RATING AND CHARACTERISTIC CURVES ( HER501 THRU HER508 )

FIG. 1 - TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1 Rise Time = 7ns max. Input Impedance = 1 megohm, 22pF.  
2 Rise Time = 10ns max. Source Impedance = 50 ohms.

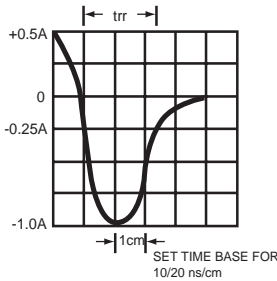


FIG. 2 - TYPICAL FORWARD CURRENT DERATING CURVE

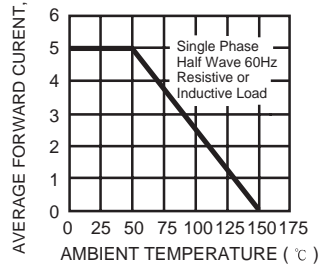


FIG. 3 - TYPICAL REVERSE CHARACTERISTICS

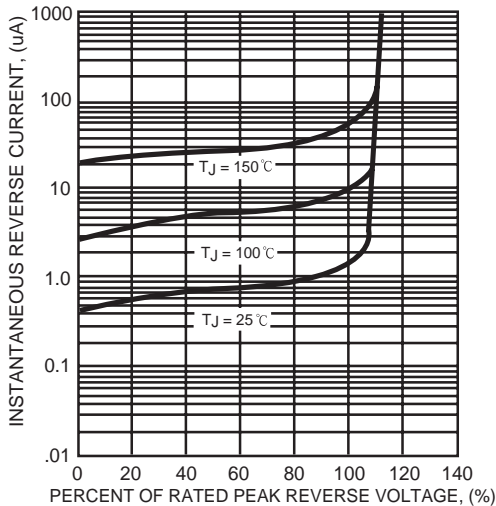


FIG. 4 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

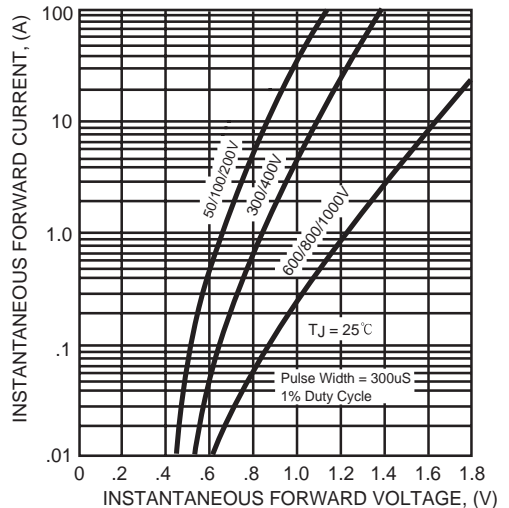


FIG. 5 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

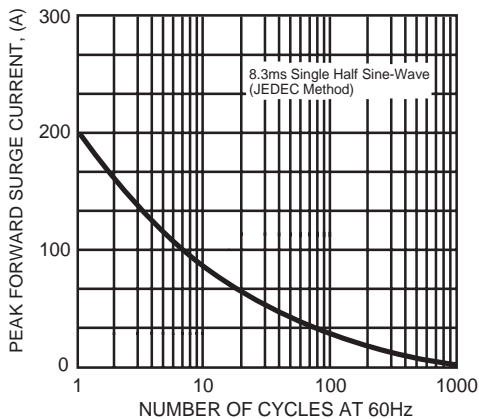
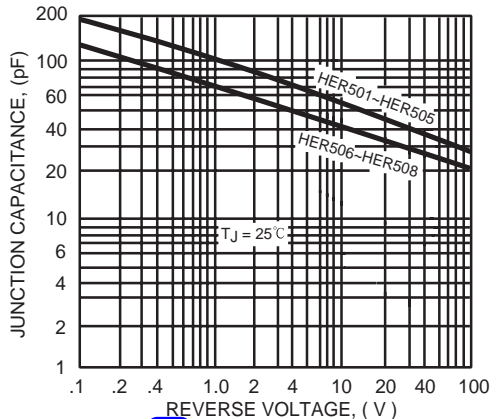


FIG. 6 - TYPICAL JUNCTION CAPACITANCE



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